



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Kwon HONG, et al.

Serial No.: 09/888,060

Group Art Unit: 2825

Filed: June 25, 2001

Examiner: Anya, Igwe U.

For: SEMICONDUCTOR MEMORY DEVICE HAVING PLUG CONTACTED TO CAPACITOR

ELECTRODE AND METHOD FOR FABRICATING THE SAME

AMENDMENT

Honorable Commissioner for Patents Washington, D.C. 20231

December 23, 2002

Sir:

Responsive to the Office Action mailed September 27, 2002 (Paper No. 7), kindly enter the following amendments and remarks.

IN THE CLAIMS:

Please amend claim 9 to read as follows:

9. (Amended) The method as recited in claim 8, the step of providing the semiconductor substrate comprising:

forming a conducting layer on the semiconductor substrate, wherein the conducting layer is electrically connected to the lower electrode via the plug.

